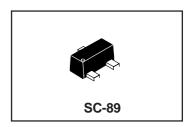
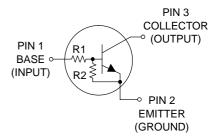


## **NPN Silicon Surface Mount Transistors with Monolithic Bias Resistor Network**

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-89 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- · Reduces Board Space
- Reduces Component Count
- The SC-89 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.





#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current	I <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Total Device Dissipation, FR-4 Board (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction–to–Ambient (Note 2)	$R_{\theta JA}$	400	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-4 @ Minimum Pad
- 2. FR-4 @  $1.0 \times 1.0$  Inch Pad



#### **ORDERING INFORMATION AND RESISTOR VALUES**

Device	Marking	R1 (K)	R2 (K)	Package	Shipping <sup>†</sup>
DTC114EET1G	8A	10	10	SC-89	3000 Tape & Reel
DTC124EET1G	8B	22	22	SC-89	3000 Tape & Reel
DTC144EET1G	8C	47	47	SC-89	3000 Tape & Reel
DTC114YET1G	8D	10	47	SC-89	3000 Tape & Reel
DTC114TET1G	94	10	∞	SC-89	3000 Tape & Reel
DTC143TET1G	8F	4.7	∞	SC-89	3000 Tape & Reel
DTC123EET1G	8H	2.2	2.2	SC-89	3000 Tape & Reel
DTC143EET1G	8J	4.7	4.7	SC-89	3000 Tape & Reel
DTC143ZET1G	8K	4.7	47	SC-89	3000 Tape & Reel
DTC124XET1G	8L	22	47	SC-89	3000 Tape & Reel
DTC123JET1G	8M	2.2	47	SC-89	3000 Tape & Reel
DTC115EET1G	8N	100	100	SC-89	3000 Tape & Reel
DTC144WET1G	8P	47	22	SC-89	3000 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characterist	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•				
Collector-Base Cutoff Current (V <sub>CB</sub> =	= 50 V, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	_	100	nAdc
Collector–Emitter Cutoff Current (V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)		I <sub>CEO</sub>	-	_	500	nAdc
Emitter–Base Cutoff Current (V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)	DTC114EET1G DTC124EET1G DTC124EET1G DTC144EET1G DTC114YET1G DTC114TET1G DTC123EET1G DTC143EET1G DTC143ZET1G DTC124XET1G DTC123JET1G DTC123JET1G DTC115EET1G DTC144WET1G	I <sub>EBO</sub>	- - - - - - - - -	- - - - - - - - -	0.5 0.2 0.1 0.2 0.9 1.9 2.3 1.5 0.18 0.13 0.2 0.05 0.13	mAdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)		V <sub>(BR)CBO</sub>	50	_	-	Vdc
Collector–Emitter Breakdown Voltage (Note 3) (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)		V <sub>(BR)CEO</sub>	50	_	_	Vdc



Characteristic	Symbol	Min	Тур	Max	Unit	
ON CHARACTERISTICS (Note 3)						
DC Current Gain	DTC114EET1G	h <sub>FE</sub>	35	60	_	
$(V_{CE} = 10 \text{ V}, I_{C} = 5.0 \text{ mA})$	DTC124EET1G		60	100	_	
,	DTC144EET1G		80	140	_	
	DTC114YET1G		80	140	_	
	DTC114TET1G		160	350	_	
	DTC143TET1G		160	350	_	
	DTC123EET1G		8.0	15	_	
	DTC143EET1G		15	30	_	
	DTC143ZET1G		80	200	_	
	DTC124XET1G		80	150	_	
	DTC123JET1G		80	140	_	
	DTC115EET1G		80	150	_	
	DTC144WET1G		80	140	_	
$(I_C = 10 \text{ mA}, I_B = 5 \text{ mA}) \text{ DTC123EET1G}$ $(I_C = 10 \text{ mA}, I_B = 1 \text{ mA}) \text{ DTC143TET1G/IDTC143EET1G/DTC143ZET1G/DTC124})$						
Output Voltage (on)		$V_{OL}$				Vdc
$(V_{CC} = 5.0 \text{ V}, V_B = 2.5 \text{ V}, R_L = 1.0 \text{ k}\Omega)$	DTC114EET1G		_	_	0.2	
	DTC124EET1G		_	_	0.2	
	DTC114YET1G		_	_	0.2	
	DTC114TET1G		_	_	0.2	
	DTC143TET1G		_	-	0.2	
	DTC123EET1G		_	-	0.2	
	DTC143EET1G		_	-	0.2	
	DTC143ZET1G		_	-	0.2	
	DTC124XET1G		_	_	0.2	
	DTC123JET1G		_	_	0.2	
$(V_{CC} = 5.0 \text{ V}, V_B = 3.5 \text{ V}, R_L = 1.0 \text{ k}\Omega)$	DTC144EET1G		_	_	0.2	
$(V_{CC} = 5.0 \text{ V}, V_B = 5.5 \text{ V}, R_L = 1.0 \text{ k}\Omega)$	DTC115EET1G		_	_	0.2	
$(V_{CC} = 5.0 \text{ V}, V_B = 4.0 \text{ V}, R_L = 1.0 \text{ k}\Omega)$	DTC144WET1G		-	_	0.2	
Output Voltage (off) ( $V_{CC}$ = 5.0 V, $V_B$ = 0.5 V, $R_L$ = 1.0 k $\Omega$ ) ( $V_{CC}$ = 5.0 V, $V_B$ = 0.25 V, $R_L$ = 1.0 k $\Omega$ ) DTC143TET1G DTC143ZET1G DTC114TET1G DTC115 EET1G		V <sub>ОН</sub>	4.9	-	-	Vdc

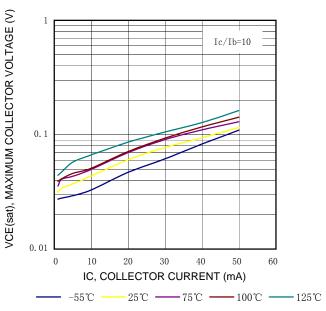
<sup>3.</sup> Pulse Test: Pulse Width < 300  $\mu$ s, Duty Cycle < 2.0%

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

	Symbol	Min	Тур	Max	Unit	
Input Resistor	DTC114EET1G	R1	7.0	10	13	kΩ
	DTC124EET1G		15.4	22	28.6	
	DTC144EET1G		32.9	47	61.1	
	DTC114YET1G		7.0	10	13	
	DTC114TET1G		7.0	10	13	
	DTC143TET1G		3.3	4.7	6.1	
	DTC123EET1G		1.5	2.2	2.9	
	DTC143EET1G		3.3	4.7	6.1	
	DTC143ZET1G		3.3	4.7	6.1	
	DTC124XET1G		15.4	22	28.6	
	DTC123JET1G		1.54	2.2	2.86	
	DTC115EET1G		70	100	130	
	DTC144WET1G		32.9	47	61.1	
Resistor Ratio	DTC114EET1G/DTC124EET1G/	R <sub>1</sub> /R <sub>2</sub>				
	DTC144EET1G/DTC115EET1G		0.8	1.0	1.2	
	DTC114YET1G DTC143TET1G/		0.17	0.21	0.25	
	DTC114TET1G DTC123EET1G/		_	_	_	
	DTC143EET1G DTC143ZET1G		0.8	1.0	1.2	
	DTC124XET1G DTC123JET1G		0.055	0.1	0.185	
	DTC144WET1G		0.38	0.47	0.56	
			0.038	0.047	0.056	
			1.7	2.1	2.6	



#### TYPICAL ELECTRICAL CHARACTERISTICS - DTC114EET1G



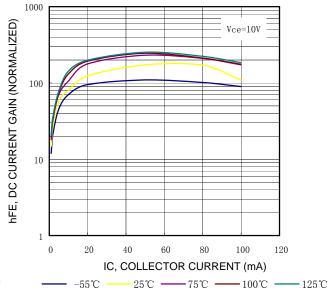


Fig. 1 VCE(sat) VS IC

Fig. 2 DC CURRENT GAIN

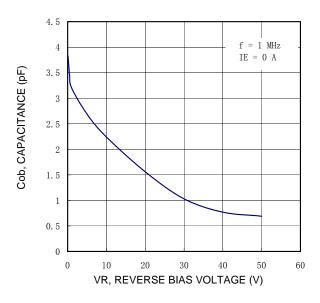


Fig. 3 OUTPUT CAPACITANCE

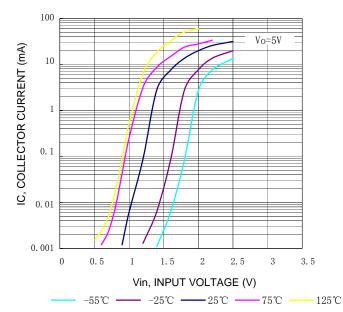


Fig. 4 OUTPUT CURRENT VS INPUT VOLTAGE



#### TYPICAL ELECTRICAL CHARACTERISTICS - DTC114EET1G

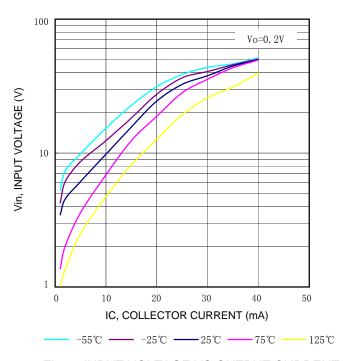


Fig. 5 INPUT VOLTAGE VS OUTPUT CURRENT



#### TYPICAL ELECTRICAL CHARACTERISTICS - DTC115EET1G

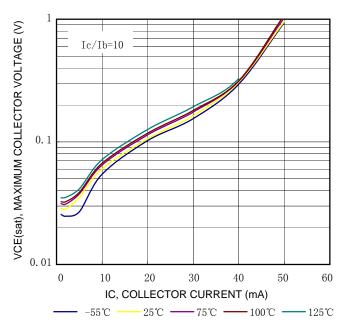


Fig. 6 VCE(sat) VS IC

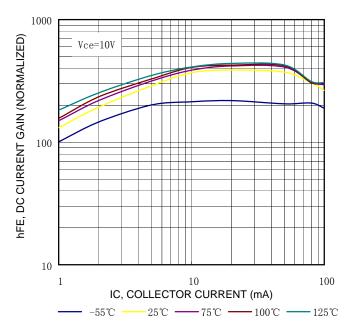


Fig. 7 DC CURRENT GAIN

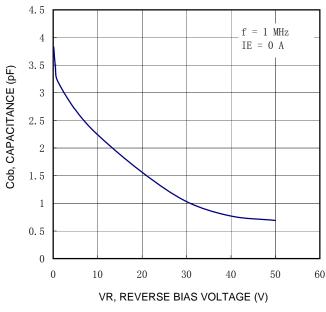


Fig. 8 OUTPUT CAPACITANCE

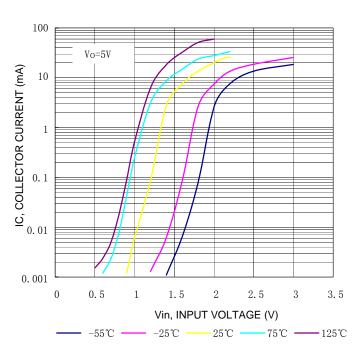


Fig. 9 OUTPUT CURRENT VS INPUT VOLTAGE



#### **TYPICAL ELECTRICAL CHARACTERISTICS - DTC115EET1G**

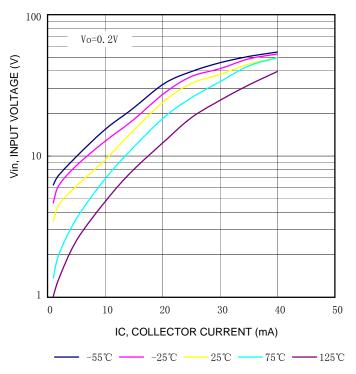


Fig. 10 INPUT VOLTAGE VS OUTPUT CURRENT



#### **TYPICAL APPLICATIONS FOR NPN BRTs**

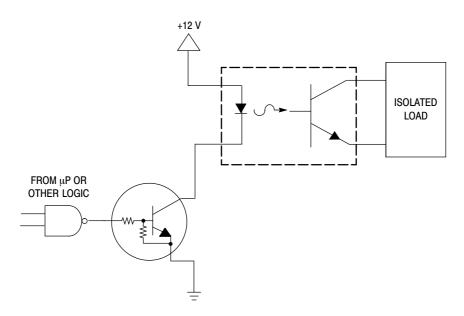


Fig. 11 LEVEL SHIFTER: CONNECTS 12 TO 24 VOLT CIRCUITS TO LOGIC

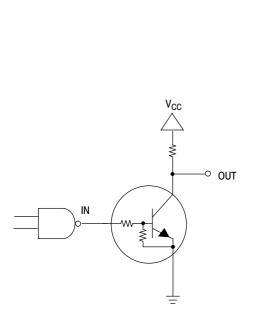


Fig. 12 OPEN COLLECTOR INVERTER: INVERTS THE INPUT SIGNAL

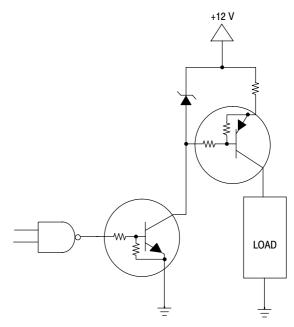
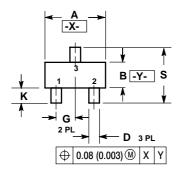
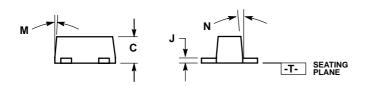


Fig. 13 INEXPENSIVE, UNREGULATED CURRENT SOURCE



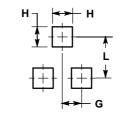
#### SC-89





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIA MATERIAL.
  4. 463C-01 OBSOLETE, NEW STANDARD 463C-02.

MILLIMETERS			INCHES			
MIN	NOM	MAX	MIN	NOM	MAX	
1.50	1.60	1.70	0.059	0.063	0.067	
0.75	0.85	0.95	0.030	0.034	0.040	
0.60	0.70	0.80	0.024	0.028	0.031	
0.23	0.28	0.33	0.009	0.011	0.013	
0.50 BSC			0.020 BSC			
	0.53 REF		0.021 REF			
0.10	0.15	0.20	0.004	0.006	0.008	
0.30	0.40	0.50	0.012	0.016	0.020	
	1.10 REF		(	0.043 REF		
		10 °			10 °	
		10 °			10 °	
1.50	1.60	1.70	0.059	0.063	0.067	
	1.50 0.75 0.60 0.23 0.10 0.30	1.50 1.60 0.75 0.85 0.60 0.70 0.23 0.28 0.50 BSC 0.53 REF 0.10 0.15 0.30 0.40 1.10 REF 	1.50	1.50	1.50	



**RECOMMENDED PATTERN** OF SOLDER PADS